

#### Continental Device India Limited

IS/ISO 9002 Lic# QSC/L- 000019.:

An IS/ISO 9002 and IECQ Certified Manufacturer

#### **NPN SILICON PLANAR TRANSISTORS**



BSX45 BSX46 BSX47

TO-39

**Metal Can Package** 

#### **AMPLIFIER TRANSISTORS**

## ABSOLUTE MAXIMUM RATINGS (Ta=25°C unless specified otherwise)

DESCRIPTION	SYMBOL	BSX45	BSX46	BSX47	UNITS
Collector Emitter Voltage	V <sub>CEO</sub>	40	60	80	V
Collector Emitter Voltage	V <sub>CES</sub>	80	100	120	V
Emitter Base Voltage	V <sub>EBO</sub>		7.0		V
Collector Current Continuous	I <sub>C</sub>		1.0		Α
Power Dissipation @ Ta=25° C	P <sub>D</sub>		1.0		W
Derate Above 25° C			5.71		mW/ °C
Power Dissipation@ Tc=25º C	P <sub>D</sub>		5.0		W
Derate Above 25° C			28.6		mW/ ºC
Operating And Storage Junction	$T_j$ , $T_{stg}$		-65 to +200		°C
Temperature Range					
THERMAL RESISTANCE					
Junction to Ambient	R <sub>th(j-a)</sub>		200		°C/W
Junction to Case	R <sub>th(j-c)</sub>		35		°C/W

## ELECTRICAL CHARACTERISTICS (Ta=25°C unless specified otherwise)

DESCRIPTION	SYMBOL	TEST CONDITION	BSX45	BSX46	BSX47	UNITS
Collector Emitter Voltage	V <sub>CEO</sub> *	$I_C=30$ mA, $I_B=0$	>40	>60	>80	V
	V <sub>CES</sub>	$I_C=100\mu A, V_{BE}=0$	>80	>100	>120	V
Emitter Base Voltage	$V_{EBO}$	$I_E=100\mu A, I_C=0$		>7.0		V
Collector Cut off Current	I <sub>CES</sub>	$V_{CE}=60V, V_{BE}=0$	<10	<10		nA
		$V_{CE}=80V, V_{BE}=0$			<10	nA
	I <sub>CES</sub>	Tc =150°C				
		$V_{CE}=60V, V_{BE}=0$	<10	<10		μΑ
		$V_{CE}=80V, V_{BE}=0$			<10	μΑ
Emitter Cut off Current	I <sub>EBO</sub>	$V_{EB}=5V$ , $I_{C}=0$		<10		nA

## **NPN SILICON PLANAR TRANSISTORS**



BSX45 BSX46 BSX47

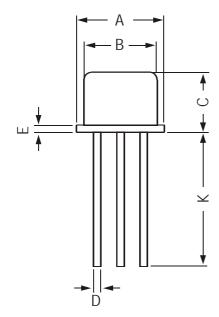
TO-39 Metal Can Package

## **ELECTRICAL CHARACTERISTICS (Ta=25°C unless specified otherwise)**

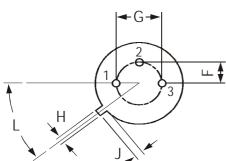
DESCRIPTION	SYMBOL	TEST CONDITION	VALUE	UNITS
DC Current Gain	h <sub>FE</sub>	I <sub>C</sub> =0.1mA,V <sub>CE</sub> =1V		
		Group -6	>10	
		Group -10	>15	
		Group -16	>25	
	h <sub>FE</sub>	I <sub>C</sub> =100mA,V <sub>CE</sub> =1V*		
		Group -6	40 to 100	
		Group -10	63 to 160	
		Group -16	100 to 250	
	h <sub>FE</sub>	I <sub>C</sub> =500mA,V <sub>CE</sub> =1V*		
		Group -6	>15	
		Group -10	>25	
		Group -16	>35	
Base Emitter on Voltage	$V_{BE(on)}^*$	I <sub>C</sub> =100mA, V <sub>CE</sub> =1V	<1.0	V
		I <sub>C</sub> =500mA, V <sub>CE</sub> =1V	0.75 to 1.5	V
		I <sub>C</sub> =1A, V <sub>CE</sub> =1V	<2.0	V
Collector Emitter Saturation Voltage	V <sub>CE(sat)</sub> *	I <sub>C</sub> =1A, I <sub>B</sub> =0.1A	<1.0	V
DYNAMIC CHARACTERISTICS	- (/			
Transition Frequency	f⊤	I <sub>C</sub> =50mA, V <sub>CE</sub> =10V	>50	MHz
		f=20MHz		
Emitter Base Capacitance	$C_{ib}$	V <sub>BE</sub> =0.5V, f=1MHz	<80	pF
Output Capacitance	C <sub>ob</sub>	V <sub>CB</sub> =10V, f=1MHz		
BSX45			<25	pF
BSX46			<20	pF
BSX47			<15	pF
Turn on time	t <sub>on</sub>	I <sub>C</sub> =100mA, I <sub>B1</sub> =-I <sub>B2</sub> =	<200	ns
Turn off time	t <sub>off</sub>	5mA	<850	ns

<sup>\*</sup>Pulse Test: Pulse Duration =300ms, Duty Cycle =1%

## **TO-39 Metal Can Package**



	DIM	MIN	MAX
	Α	8.50	9.39
	В	7.74	8.50
	С	6.09	6.60
	D	0.40	0.53
	E		0.88
	F	2.41	2.66
	G	4.82	5.33
l	Н	0.71	0.86
	J	0.73	1.02
	K	12.70	_
	L	42 DEG	48 DEG





All dimensions are in mm

PIN CONFIGURATION

- 1. EMITTER
- 2. BASE
- 3. COLLECTOR

# Packing Detail

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight /Qty	Size	Qty	Size	Qty	Gr Wt
TO-39	500 pcs/polybag	540 gm/500 pcs	3" x 7.5" x 7.5"	20K	17" x 15" x 13.5"	32K	40 kgs

Notes BSX45
BSX46

BSX47

**TO-39** 

**Metal Can Package** 

#### **Disclaimer**

The product information and the selection guides facilitate selection of the CDIL's Discrete Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished in the Data Sheet and on the CDIL Web Site/CD is believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Discrete Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

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CDIL is a registered Trademark of
Continental Device India Limited
C-120 Naraina Industrial Area, New Delhi 110 028, India.
Telephone + 91-11-579 6150 Fax + 91-11-579 9569, 579 5290
e-mail sales@cdil.com www.cdil.com

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